

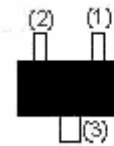
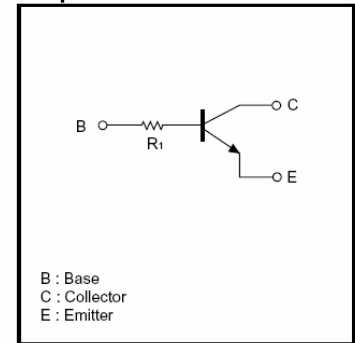
NPN DIGITAL TRANSISTOR

 Lead(Pb)-Free

Features:

- * Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- * The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- * Only the on/off conditions need to be set for operation, making device design easy.

Equivalent circuit



- (1) Base
- (2) Emitter
- (3) Collector

Abbreviated symbol: 06

MAXIMUM RATINGS* $T_A=25^{\circ}\text{C}$ unless otherwise noted

Parameter	Symbol	Value	Units
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current -Continuous	I_{C}	100	mA
Collector Dissipation	P_{C}	200	mW
Junction temperature	T_{J}	150	$^{\circ}\text{C}$
Junction and Storage Temperature	T_{stg}	-55~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_{\text{amb}}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage $I_{\text{C}}=50\mu\text{A}, I_{\text{E}}=0$	$V_{(\text{BR})\text{CBO}}$	50			V
Collector-emitter breakdown voltage $I_{\text{C}}=1\text{mA}, I_{\text{B}}=0$	$V_{(\text{BR})\text{CEO}}$	50			V
Emitter-base breakdown voltage $I_{\text{E}}=50\mu\text{A}, I_{\text{C}}=0$	$V_{(\text{BR})\text{EBO}}$	5			V
Collector cut-off current $V_{\text{CB}}=50\text{V}, I_{\text{E}}=0$	I_{CBO}			0.5	μA
Emitter cut-off current $V_{\text{EB}}=4\text{V}, I_{\text{C}}=0$	I_{EBO}			0.5	μA
DC current gain $V_{\text{CE}}=5\text{V}, I_{\text{C}}=1\text{mA}$	h_{FE}	100	300	600	
Collector-emitter saturation voltage $I_{\text{C}}=5\text{mA}, I_{\text{B}}=0.5\text{mA}$	$V_{\text{CE}(\text{sat})}$			0.3	V
Transition frequency $V_{\text{CE}}=10\text{V}, I_{\text{E}}=-5\text{mA}, f=100\text{MHz}$	f_{T}		250		MHz
Input resistor	R1	32.9	47	61.1	$\text{k}\Omega$

Typical Characteristics

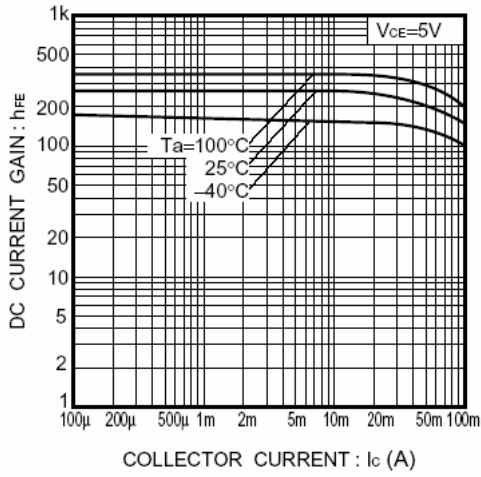


Fig.1 DC current gain vs. collector current

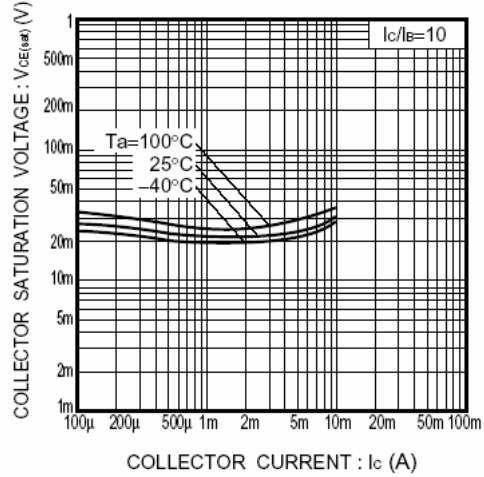
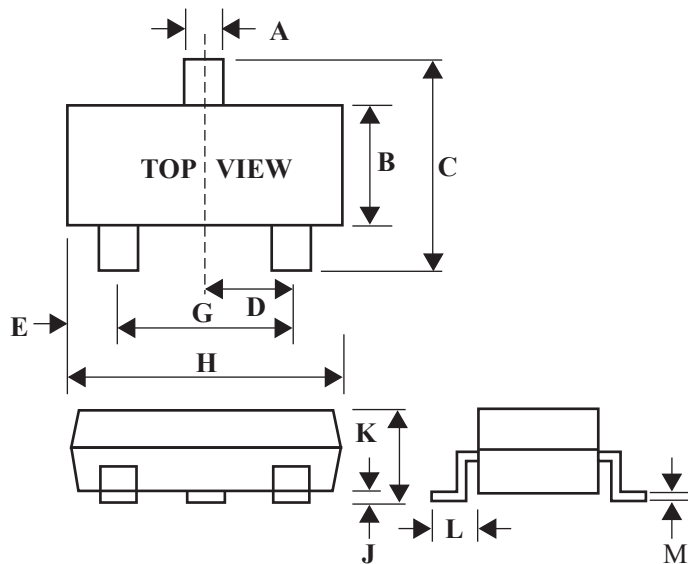


Fig.2 Collector-emitter saturation voltage vs. collector current

SOT-23 Outline Dimensions

Unit:mm



Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25